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|---|---|
|  | <h2>SI3850ADV-T1-E3</h2>  |
|   | <p><b>Hersteller-Teilenummer:</b> SI3850ADV-T1-E3</p> <p><b>Hersteller / Marke:</b> Vishay / Siliconix</p> <p><b>Teil der Beschreibung:</b> MOSFET N/P-CH 20V 1.4A 6TSOP</p> <p><b>Datenblätter:</b>  <a href="#">SI3850ADV-T1-E3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 20463 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p> |
| <p>Image may be representation.<br/>See specs for product details.</p>            |   |

### Spezifikationen

|  |  |
|--|--|
| Teilenummer                                      | SI3850ADV-T1-E3                                  |
| Hersteller                                       | Vishay / Siliconix                               |
| Beschreibung                                     | MOSFET N/P-CH 20V 1.4A 6TSOP                     |
| Kategorie  | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus                                       | 20463 pcs Stock                                  |
| Serie  | TrenchFET®                                       |
| Betriebstemperatur                               | -55°C ~ 150°C (TJ)                               |
| Befestigungsart                                  | Surface Mount                                    |
| Leistung - max                                   | 1.08W  |
| Verpackung / Gehäuse                             | SOT-23-6 Thin, TSOT-23-6                         |
| Supplier Device-Gehäuse                          | 6-TSOP   |
| Typ FET  | N and P-Channel, Common Drain                    |
| FET-Merkmal                                      | Logic Level Gate                                 |
| Drain-Source-Spannung (Vdss)                     | 20V  |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 1.4A, 960mA                                      |
| Rds On (Max) @ Id, Vgs                           | 300 mOhm @ 500mA, 4.5V                           |
| VGS (th) (Max) @ Id                              | 1.5V @ 250µA                                     |
| Gate Charge (Qg) (Max) @ Vgs                     | 1.4nC @ 4.5V                                     |
| Eingabekapazität (Ciss) (Max) @ Vds              | -  |
| Verpackung                                       | Tape & Reel (TR)                                 |



















































SI3850ADV-T1-E3 ist neu im Original, Suche SI3850ADV-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3850ADV-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI3850ADV-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

|   |  |  |   |
|---|--|--|---|
|  <p><b>SI3850ADV-T1-E3</b><br/>Electro-Films (EFI) / Vishay<br/>MOSFET N/P-CH 20V 1.4A<br/>6TSOP</p> |  <p><b>SI3831DV-T1-E3</b><br/>Electro-Films (EFI) / Vishay<br/>IC PWR SW BI-DIR PCHAN<br/>6TSOP</p> |  <p><b>SI3850DV-T1</b><br/>VISHAY<br/>SI3850DV-T1 VISHAY</p>       |  <p><b>SI3831DV-T1-E3</b><br/>Vishay / Siliconix<br/>IC PWR SW BI-DIR PCHAN<br/>6TSOP</p>            |
|  <p><b>SI3831DV-T1-GE3</b><br/>Vishay / Siliconix<br/>IC PWR SW BI-DIR PCHAN<br/>6TSOP</p>           |  <p><b>SI3850ADV-T1-GE3</b><br/>Vishay / Siliconix<br/>MOSFET N/P-CH 20V 1.4A 6-<br/>TSOP</p>       |  <p><b>SI3850DV-T1-E3</b><br/>VISHAY<br/>SI3850DV-T1-E3 VISHAY</p> |  <p><b>SI3831DV-T1-GE3</b><br/>Electro-Films (EFI) / Vishay<br/>IC PWR SW BI-DIR PCHAN<br/>6TSOP</p> |

### heiße Teile

Mehr

|  |  |  |   |   |
|--|--|--|---|---|
|  SI3585DV-T1-E3   |  SI3585DV-T1-E3   |  SI3585DV-T1-GE3  |  SI3585DV-T1-GE3  |  SI3586DS-TI-E3  |
|  SI3586DV         |  SI3586DV-T1-E3   |  SI3586DV-T1-E3   |  SI3586DV-T1-GE3  |  SI3586DV-T1-GE3 |
|  SI3588DV         |  SI3588DV-T1-E3   |  SI3588DV-T1-E3   |  SI3588DV-T1-GE3  |  SI3588DV-T1-GE3 |
|  SI3590DV-T1-GE3  |  SI3590DV-T1-GE3  |  SI3801DV-T1      |  SI3803DV-T1      |  SI3805DV-T1     |
|  SI3805DV-T1-E3   |  SI3805DV-T1-E3   |  SI3812DV-T1-GE3  |  SI3812DV-T1-GE3  |  SI3850ADV-T1-E3 |
|  SI3850ADV-T1-GE3 |  SI3850ADV-T1-GE3 |  SI3850DV-T1      |  SI3850DV-T1-E3   |  SI3850DV-T1-GE3 |
|  SI3851DV         |  SI3851DV-T1      |  SI3851DV-T1-E3   |  SI3851DV-T1-E3   |  SI3851DV-T1-GE3 |
|  SI3853DV-T1-E3   |  SI3853DV-T1-E3   |  SI3861BDV-T1-GE3 |  SI3861BDV-T1-GE3 |  SI3861DV-NL     |
|  SI3861DV-T1-E3   |  SI3863BDV-T1-GE3 |  SI3863DV-T1-E3   |  SI3863DV-T1-GE3  |  SI3865BDV-T1-E3 |
|  SI3865BDV-T1-E3  |  SI3865CDV-T1-GE3 |  SI3865CDV-T1-GE3 |  SI3865DV-T1      |  SI3865DV-T1-E3  |

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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